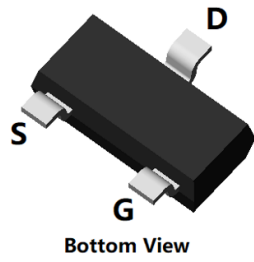
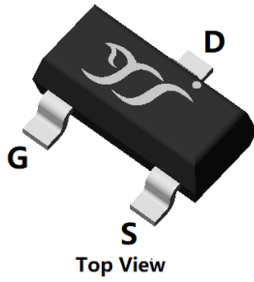
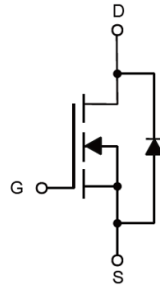


N-Channel Enhancement Mode Field Effect Transistor



SOT-23



Product Summary

- V_{DS} 20V
- I_D 4.5A
- $R_{DS(ON)}$ (at $V_{GS}=4.5V$) <25m Ω
- $R_{DS(ON)}$ (at $V_{GS}=2.5V$) <32m Ω

General Description

- Trench Power MV MOSFET technology
- High Speed switching
- Moisture Sensitivity Level 1
- Epoxy Meets UL 94 V-0 Flammability Rating
- Halogen Free

Applications

- PWM application
- Load switch

Absolute Maximum Ratings ($T_A=25^\circ C$ unless otherwise noted)

Parameter		Symbol	Limit	Unit
Drain-source Voltage		V_{DS}	20	V
Gate-source Voltage		V_{GS}	± 10	V
Drain Current	$T_A=25^\circ C$	I_D	4.5	A
	$T_A=100^\circ C$		2.8	
Pulsed Drain Current ^A		I_{DM}	30	A
Total Power Dissipation ^B	$T_A=25^\circ C$	P_D	1	W
	$T_A=100^\circ C$		0.4	
Junction and Storage Temperature Range		T_J, T_{STG}	-55~+150	$^\circ C$

Thermal resistance

Parameter		Symbol	Typ	Max	Units
Thermal Resistance Junction-to-Ambient ^C	Steady-State	$R_{\theta JA}$	100	125	$^\circ C/W$

Ordering Information (Example)

PREFERRED P/N	PACKING CODE	Marking	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
YJL2300C	F2	2300C.	3000	30000	120000	7" reel



YJL2300C

RECOMMEND
YJL2300A
FOR NEW DESIGN

■ Electrical Characteristics (T_J=25°C unless otherwise noted)

Parameter	Symbol	Conditions	Min	Typ	Max	Units
Static Parameter						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250μA	20	-	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =20V, V _{GS} =0V	-	-	1	μA
		V _{DS} =20V, V _{GS} =0V, T _J =150°C	-	-	100	
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±10V, V _{DS} =0V	-	-	±100	nA
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =250μA	0.4	0.6	1	V
Static Drain-Source On-Resistance	R _{DS(on)}	V _{GS} =4.5V, I _D =4.5A	-	20	25	mΩ
		V _{GS} =2.5V, I _D =3A	-	25	32	
		V _{GS} =1.8V, I _D =2.7A	-	33	46	
Diode Forward Voltage	V _{SD}	I _S =4.5A, V _{GS} =0V	-	0.9	1.2	V
Gate resistance	R _G	f=1MHz, Open drain	-	2.7	-	Ω
Maximum Body-Diode Continuous Current	I _S		-	-	4.5	A
Dynamic Parameters						
Input Capacitance	C _{iss}		-	390	-	pF
Output Capacitance	C _{oss}	V _{DS} =10V, V _{GS} =0V, f=1MHz	-	75	-	
Reverse Transfer Capacitance	C _{rss}		-	70	-	
Switching Parameters						
Total Gate Charge	Q _g		-	12.5	-	nC
Gate-Source Charge	Q _{gs}	V _{GS} =10V, V _{DS} =10V, I _D =4.5A	-	1	-	
Gate-Drain Charge	Q _{gd}		-	2.5	-	
Reverse Recovery Charge	Q _{rr}		-	3.5	-	nC
Reverse Recovery Time	t _{rr}	I _F =4.5A, di/dt=150A/us	-	10	-	ns
Turn-on Delay Time	t _{D(on)}		-	4.5	-	ns
Turn-on Rise Time	t _r	V _{GS} =10V, V _{DD} =10V, I _D =4.5A R _{GEN} =2.2Ω	-	28	-	
Turn-off Delay Time	t _{D(off)}		-	21	-	
Turn-off fall Time	t _f		-	2.5	-	

A. Repetitive rating; pulse width limited by max. junction temperature.

B. P_d is based on max. junction temperature, using junction-case thermal resistance.

C. The value of R_{θJA} is measured with the device mounted on the minimum recommend pad size, in the still air environment with T_A=25°C.



The maximum allowed junction temperature of 150°C. The value in any given application depends on the user's specific board design.

■ Typical Electrical and Thermal Characteristics Diagrams

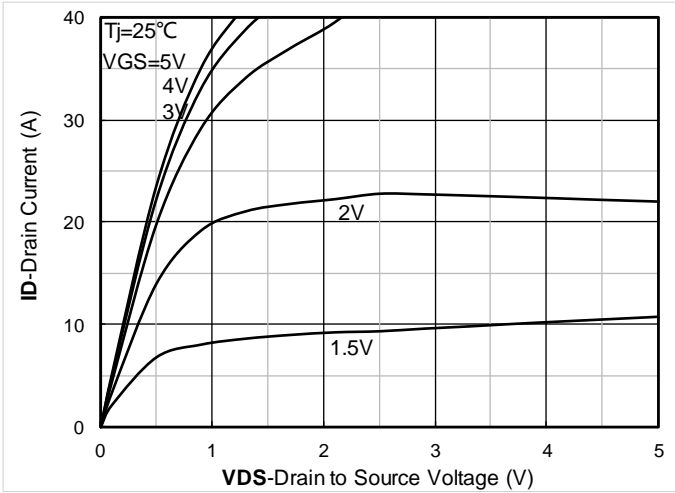


Figure 1. Output Characteristics

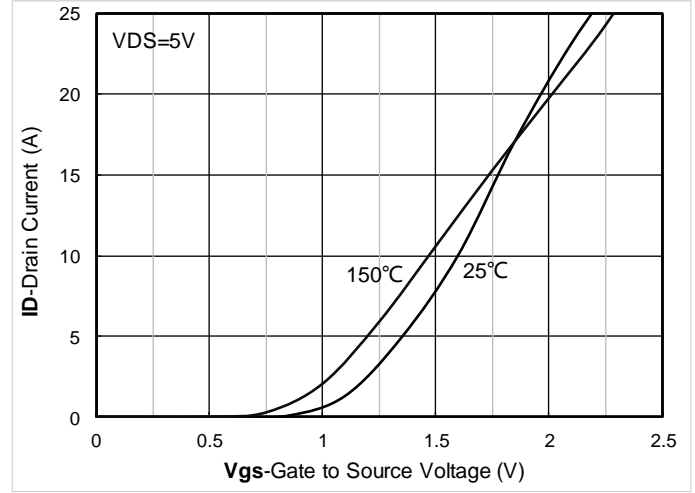


Figure 2. Transfer Characteristics

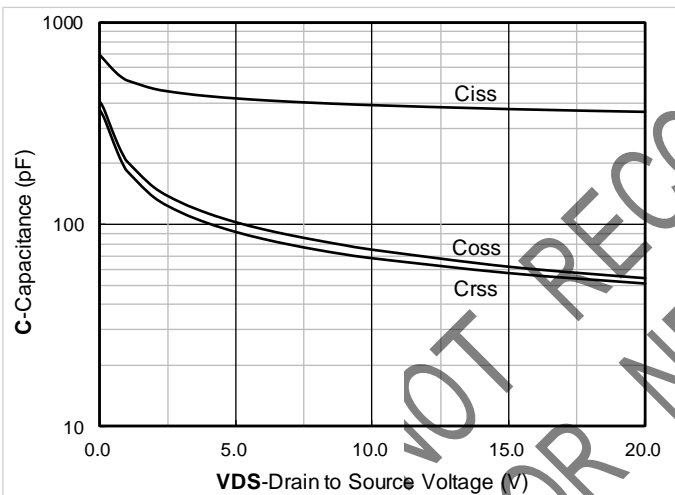


Figure 3. Capacitance Characteristics

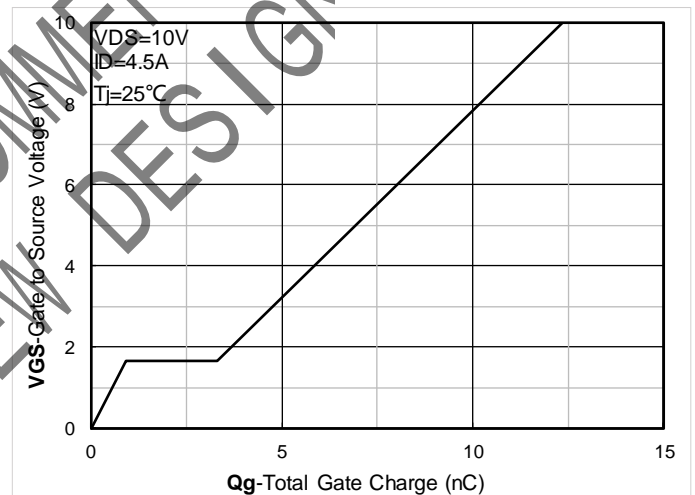


Figure 4. Gate Charge

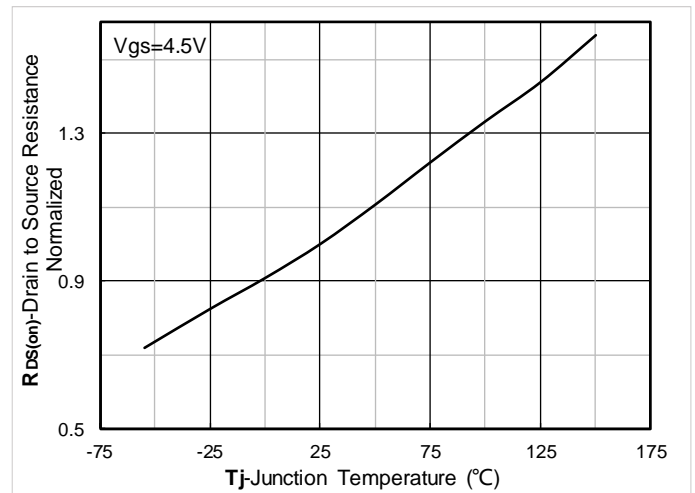
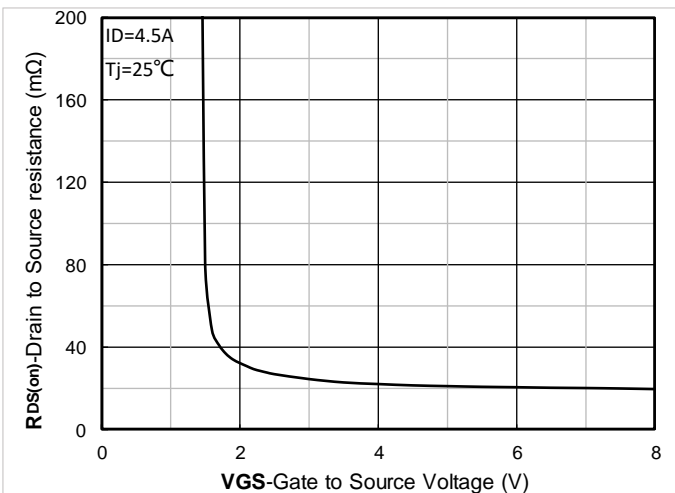




Figure 5. On-Resistance vs Gate to Source Voltage

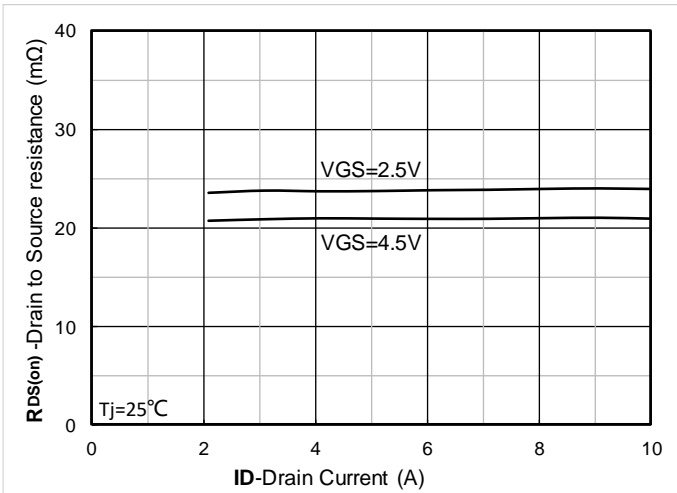


Figure 7. $R_{DS(on)}$ VS Drain Current

Figure 6. Normalized On-Resistance

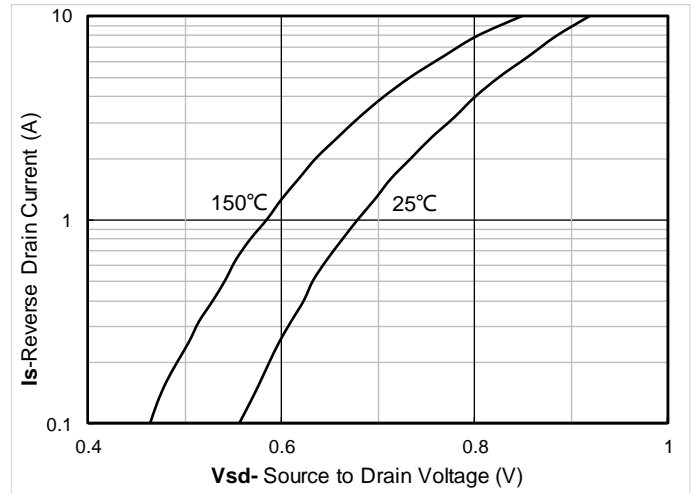


Figure 8. Forward characteristics of reverse diode

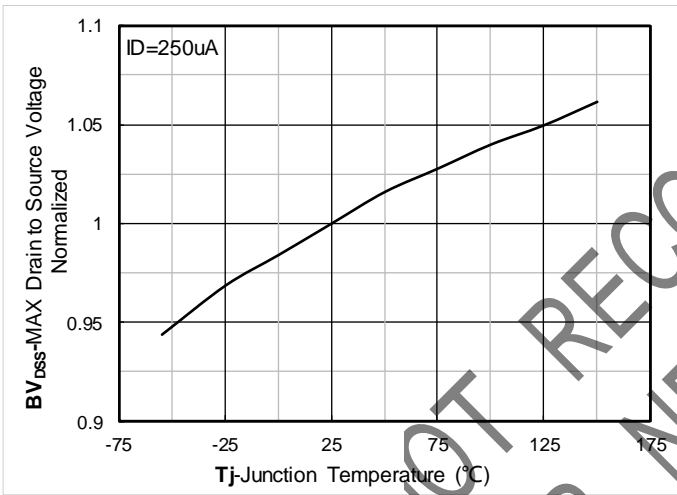


Figure 9. Normalized breakdown voltage

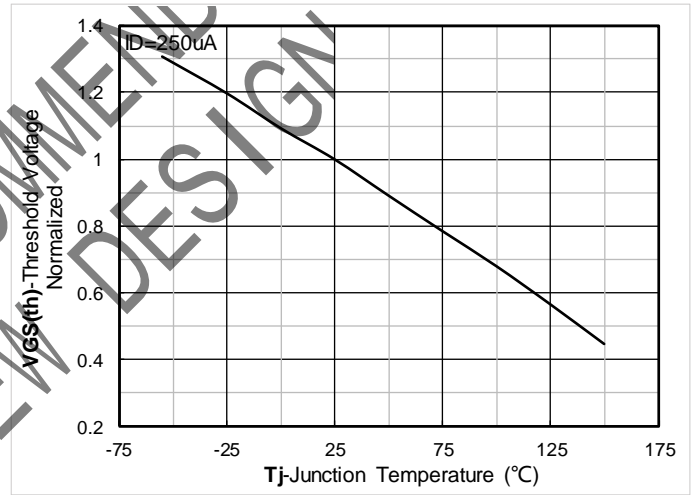


Figure 10. Normalized Threshold voltage

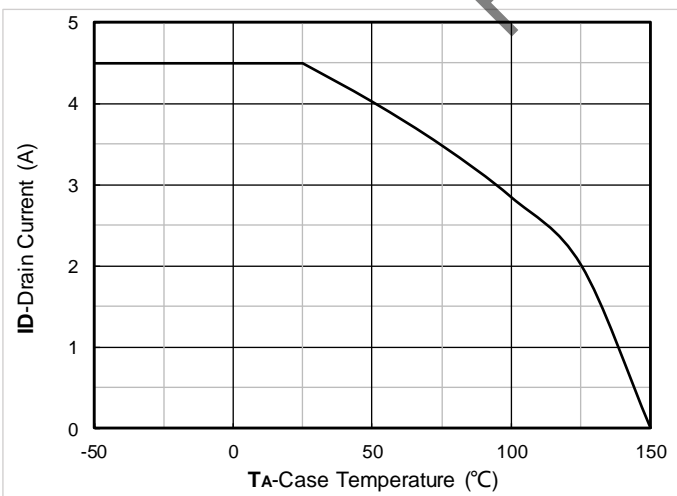


Figure 11. Current dissipation

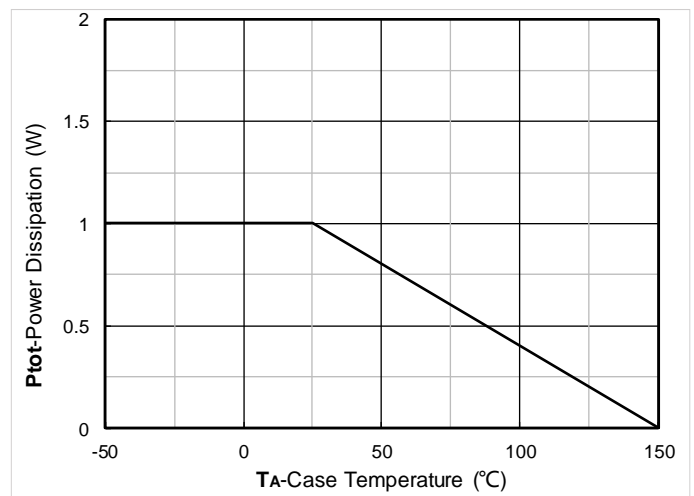


Figure 12. Power dissipation

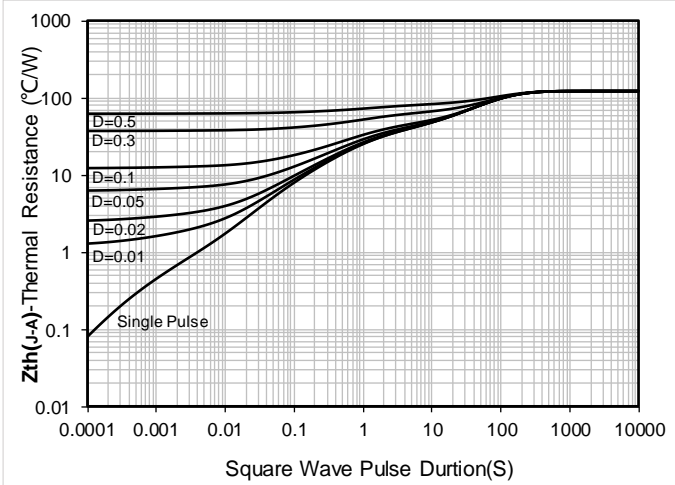


Figure 13. Maximum Transient Thermal Impedance

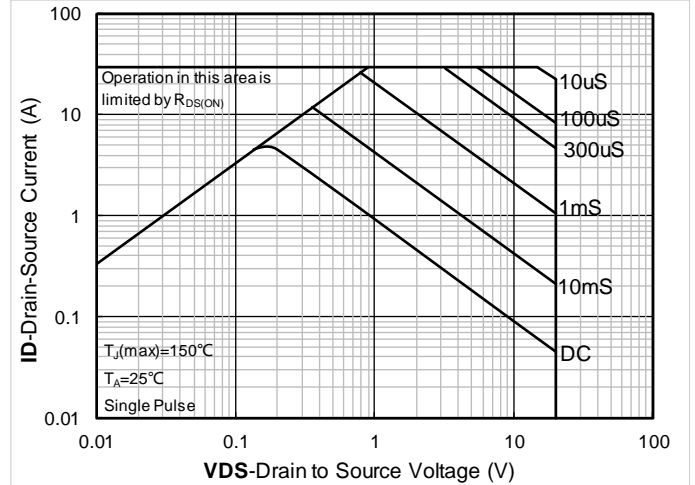


Figure 14. Safe Operation Area

■ Test Circuits & Waveforms

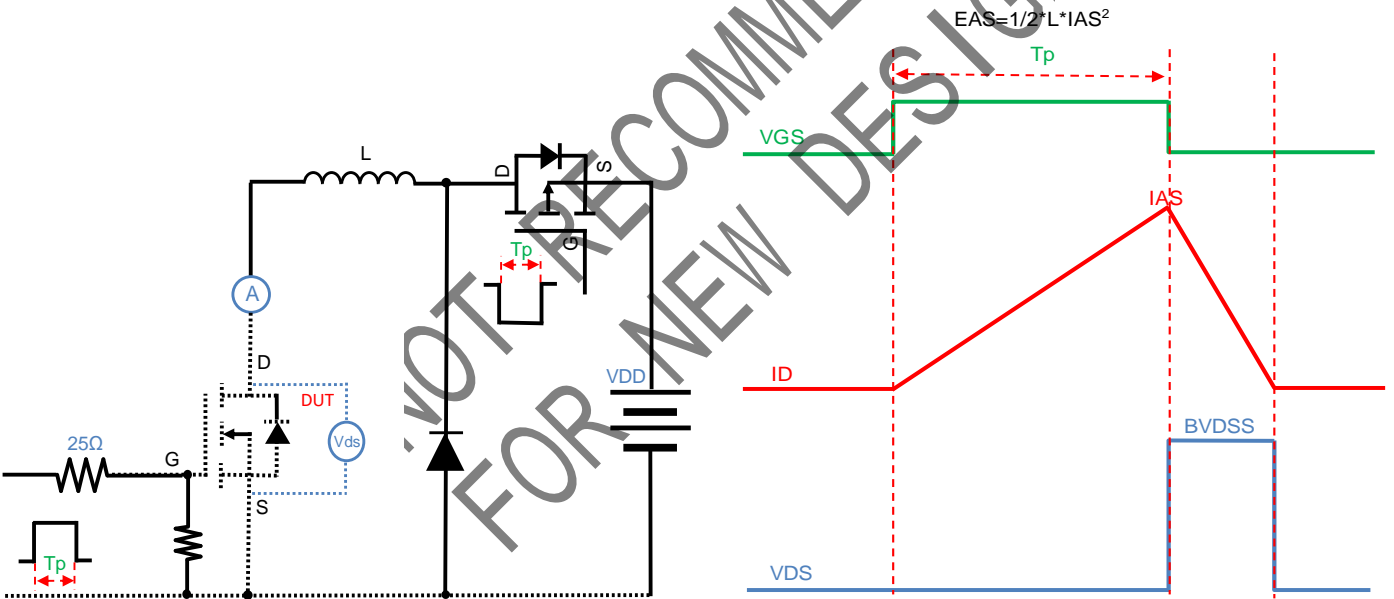


Figure A. Unclamped Inductive Switching (UIS) Test Circuit & Waveform

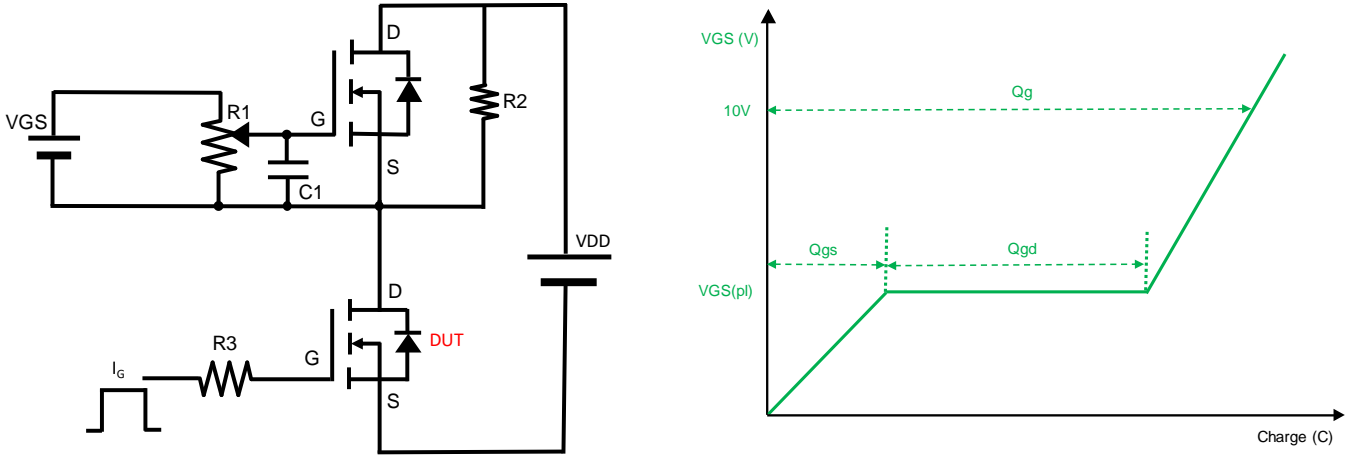


Figure B. Gate Charge Test Circuit & Waveform

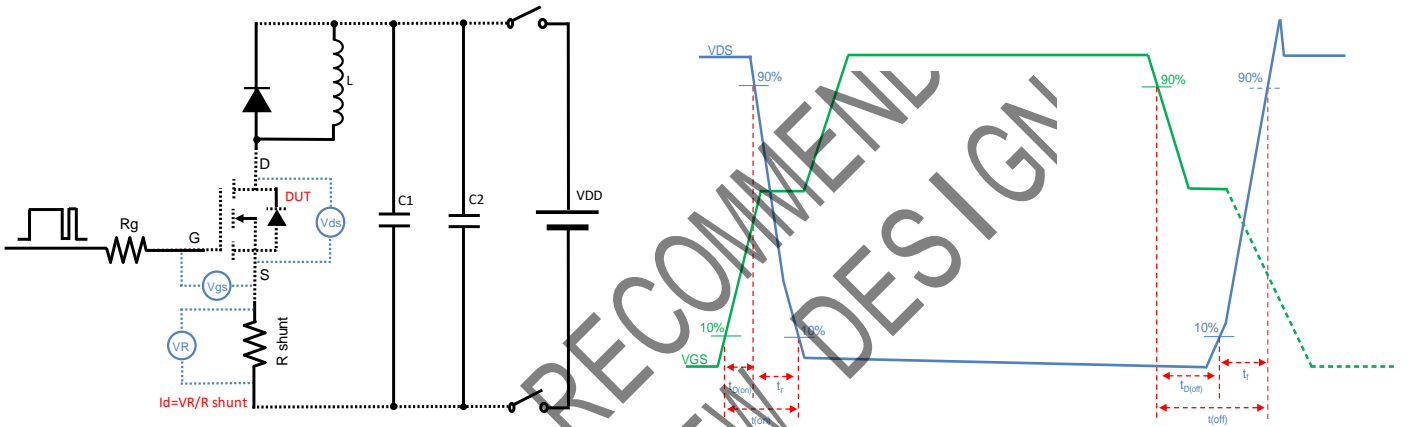


Figure C. Resistive Switching Test Circuit & Waveform

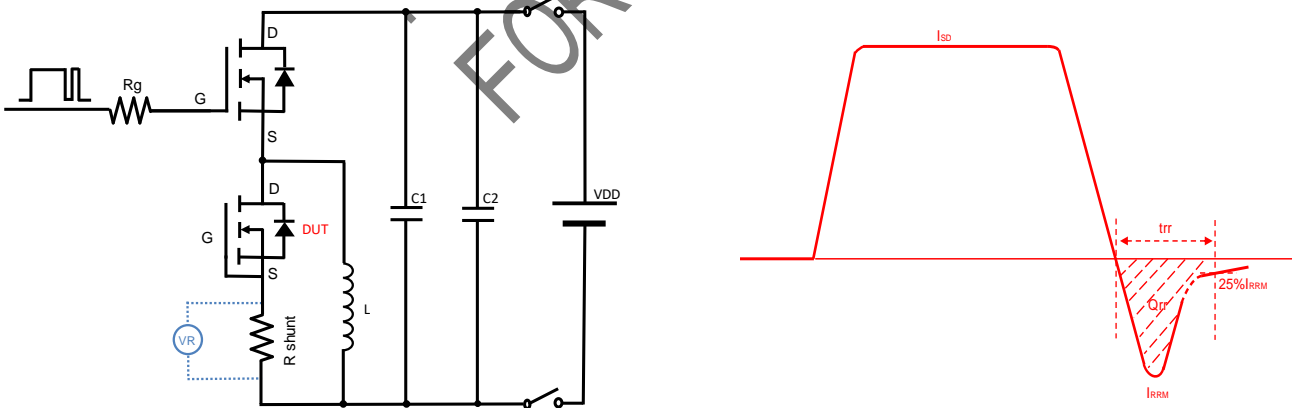
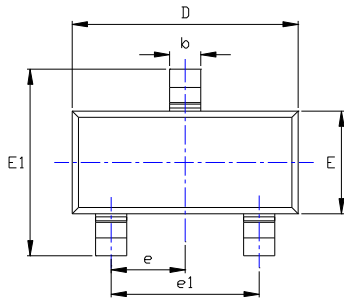
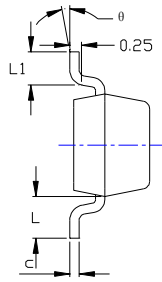


Figure D. Diode Recovery Test Circuit & Waveform

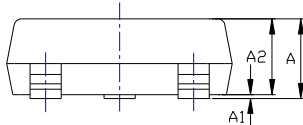
■ SOT-23 Package information



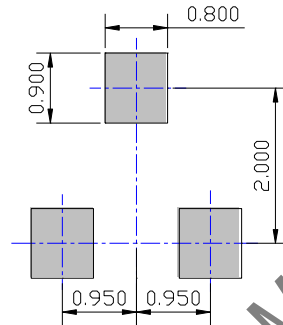
TOP VIEW



SIDE VIEW



SIDE VIEW



UNIT: mm

SUGGESTED SOLDER PAD LAYOUT

SYMBOL	DIMENSIONS			
	INCHES		Millimeter	
	MIN.	MAX.	MIN.	MAX.
A	0.035	0.045	0.900	1.150
A1	0.000	0.004	0.000	0.100
A2	0.035	0.041	0.900	1.050
b	0.012	0.020	0.300	0.500
c	0.004	0.008	0.100	0.200
D	0.110	0.118	2.800	3.000
E	0.047	0.055	1.200	1.400
E1	0.089	0.100	2.250	2.550
e	0.037TYP		0.950TYP	
e1	0.071	0.079	1.800	2.000
L	0.028REF		0.550REF	
L1	0.012	0.200	0.300	0.500
θ	0°	8°	0°	8°

NOTE:
 1. PACKAGE BODY SIZES EXCLUDE MOLD FLASH AND GATE BURRS.
 2. TOLERANCE 0.1mm UNLESS OTHERWISE SPECIFIED.
 3. THE PAD LAYOUT IS FOR REFERENCE PURPOSES ONLY.

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